Enhancement of optical properties and dielectric nature of Sm³⁺doped Na₂O-ZnO-TeO₂Glass materials

Jyotindra Nath Mirdda¹, Subhadipta Mukhopadhyay¹, Kriti Ranjan Sahu^{2*}, Makhanlal Nanda

Goswami³

¹Dept. of Physics, Jadavpur University, Kolkata, 700032, India

²Dept. of Physics, Bhatter College, Dantan, Paschim Midnapore, West Bengal, 721426, India ³Dept. of Physics, Midnapore College, Paschim Midnapore, West Bengal, 721101, India

Abstract

Samarium doped Na₂O-ZnO-TeO₂ (NZT) glasses were prepared by the melt quenching method. The glass-forming ability and glass stability of prepared glass was estimated by Hruby parameter using Differential Thermal Analysis (DTA) and Thermo-gravimetric Analysis (TGA). The study of FTIR spectra and X-ray diffraction described the ionic nature and the amorphous pattern of glass respectively. The absorption peaks were observed for the transitions ${}^{6}H_{5/2}$ - ${}^{4}P_{3/2}$ at 402 nm, ${}^{6}H_{5/2}$ - ${}^{4}M_{19/2}$ at 418 nm, ${}^{6}H_{5/2}$ - ${}^{4}I_{15/2}$ at 462 nm and ${}^{6}H_{5/2}$ - ${}^{4}I_{11/2}$ at 478 nm in the absorption spectra. The optical band gap energy (Eg) was calculated and observed to be decreased from 2.95 eV to 1.50 eV with doping concentration. The visible emission band was observed in the Sm³⁺ doped glass samples. The variation of dielectric constant with frequency was found to be independent for the frequency range 3 kHz - 2 MHz. The measurement of temperature-dependent dc conductivity showed Arrhenius type mechanism of conduction.

Keywords: Thermal analysis, FTIR, UV-Vis absorption, Fluorescence, Dielectric constant.

Corresponding Author: Kriti Ranjan Sahu, Email: <u>kriti.basis2020@gmail.com</u>, Mobile Phone: +91-8250808742

1. Introduction

Tellurium di-oxideTeO₂ is a promising glass network maker in the existence of alkali, alkaline earth and transition metal oxides (TMO) as modifiers, but it does not form glass itself. So, TeO₂ is familiar as a conditional glass producer, as it requires a modifier to produce the glassy state of the materials. Tellurite glass materials have some interesting properties like transparency at room temperature, hardness of satisfactory strength and attractive corrosion resistance [1-3]. Tellurite glasses are very interesting materials for linear and non-linear applications in optics, due to their significant characteristics such as low melting point, small phonon energy and large refractive index. It has also important for high dielectric constant, good chemical durability, high thermal stability, non-hygroscopic, with a large transmission window and the possibility to integrate a large quantity of rare-earth ions. It can be also applied as micro-lenses in photocopiers and mobile-phone cameras, IC photo masking in photolithography, photosensitive glass, hard disks, substrates for solar cells, artificial bones for mankind and dental transplants, etc. Glass materials are practically used for optical appliances due to their various compositions, physical isotropy and deficiency of grain boundaries. Tellurite glasses are useful to study by industrial researchers not only because of their methodological applications, but also owing to a fundamental significance in thoughtful their microscopic mechanisms [4, 5].

The luminescence properties of optical materials have been broadly observed not only for applications in phosphors, scintillators and laser crystals but also for scientific importance during the last two decays [6-12]. In presence of rare-earth ions, the glass materials are excellent luminescence intensity because of their emission power due to 4f-4f and 4f-5d electronic transitions [13-15].

Rare-Earth ions (RE^{3+}) doped tellurite glasses are applied due to their large potential in optoelectronic instruments such as solid-state lasers optical switches, broad-band amplifications, nonlinear optical devices, infra-red (NIR) laser windows, optical fibers three-dimensional displays, optical amplifiers, field emission displays, colour displays white light-emitting diodes, high-density optical data reading, biomedical diagnostics, microchip lasers, planar waveguides and high-density frequency domain optical data storage[16]. Samarium (Sm^{3+}) can be used as a dopant in glass hosts for powerful emissions in the visible area. Especially, the reddish-orange emission section from Sm_2O_3 doped NZT glasses holds strong photo-luminescence intensity, large emission cross-section and high quantum efficiency, which could be fit for laser applications. Therefore, Sm^{3+} ions are the significant luminescent activators that are useful in illustrating the fluorescence properties because its ${}^4G_{5/2}$ level shows comparatively high quantum efficiency [4].

In this present work, the focus has been made to study properly the glass formation, structural, optical and electrical properties at room temperature of Sm^{3+} doped Na₂O-ZnO-TeO₂ (NZT) glass compounds.

2. Experimental

The melt quenching process was used to prepare pure and Sm^{3+} doped Na₂O-ZnO-TeO₂ (NZT) glasses using research-grade initial composition Zinc Oxide (ZnO), Tellurium di-Oxide (TeO₂), Sodium Carbonate (Na₂CO₃) manufactured by Merck and Samarium Oxide (Sm₂O₃) made by LobaChemie. The mixing ratio of Na₂O, ZnO and TeO₂ is continued as 1:2:7 to make the host glass matrix. Samarium Oxide (Sm₂O₃) was added to the glass system as a dopant for (0-2) wt%. The standardized mixture of these precursors was obtained by grinding the ingredient

powders in agate mortar. The mixture was put in an alumina crucible and the crucible was kept in an electrical furnace. The melt quenching method was reached by two stages of heating with the temperature at 400 °C for 1 hour and temperature at 475 °C for half an hour to prepare the good quality telluride glass. The cylindrical stainless-steel plate was used to hold the melted sample for quenching and the prepared glass material was placed again in the furnace at 400°C for 1 hour to anneal the sample. The annealed glass was allowed to reach room temperature gradually through the slow cooling process to avoid thermal stress.

DTA/TGA of the initial mixtures (raw materials in the powder form) were carried out through the argon environment by using PerkinElmer Instrument (Pyris Diamond TG/DTA, thermogravimetric/differential thermal analyzer) for the temperature region of 30 °C to 650 °C with a scanning rate of 10°C/min. X-ray diffraction patterns were obtained using an X-ray diffractometer (RIGAKU model: Japan, XRD 6000, $\lambda = 1.5418$ Å) with a slow-scanning rate 3°/min between the angle 10° and 70° for all the samples. FTIR spectrometer (HITACHI Model F-700) was used to detect the type of pure and doped glasses in the wave number region 400-3000 cm⁻¹. Absorption spectra and emission band of all the glasses were found using UV/VIS/NIR spectrophotometer (Perkin Elmer Lambda-35) for the wavelength range 400-800 nm and fluorescence spectrophotometer (HITACHI Model F-7000) for 300-600 nm at room temperature. The dielectric constants (ε) of prepared glass materials were measured using LCR-HiTESTER (HIOKI, Japan) for the wide frequency range of 100 Hz-8 MHz at room temperature. The temperature-dependent DC conductivity of glass samples was studied for the temperature range 36 °C-227 °C using constant voltage supply and current meter.

3. Results and Discussion

Figure1 shows the transparent Sm_2O_3 doped NZT glass samples. The colour of the pure NZT glass is white, while Sm^{3+} doped NZT glasses are turned into yellowish colour due to the higher doping of Sm^{3+} ions in the NZT glass samples. There are no visible crystallites present in these transparent samples.

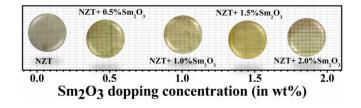


Figure 1 Picture of Sm₂O₃ doped NZT glass sample.

3.1. Thermal properties

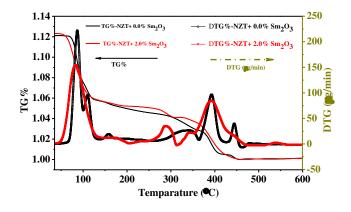


Figure 2 DTA curves of Sm₂O₃ doped NZT glass samples.

Figure 2 shows the DTA curve of the pure and Sm_2O_3 doped (2.0% wt) NZT glasses from 40 °C to 550 °C at a heating rate of 10 °C/min. Three consecutive endothermic peaks have been found in DTA curve between (72 - 160) °C for pure and doped NZT glasses. These endothermic peaks on the DTA pattern are attributed to the desorption or exclusion of moisture. Generally endothermic peaks are evolved due to the melting point and exothermic peak indicates the crystallization of the melted glass [17]. Also, the exothermic peaks occurred when the CO₂ is

released from the precursor powders and that has been found at around 406°C for pure and 416 °C for doped NZT glass.

Table 1 Thermal parameters calculated from the DTA traces of pure and Sm₂O₃ doped NZT

Sample Name	$T_{g}(^{\circ}C)$	$T_{c}(^{\circ}C)$	T_m (°C)	$\Delta T = T_c - T_g$	$H = (T_c - T_g)/(T_m - T_c)$
NZT+0.0% Sm ₂ O ₃	284	328	447	122	0.37
NZT+2.0% Sm ₂ O ₃	275	336	443	61	0.57

glasses.

These curves also suggest that the phase transition occurred due to the transition of solid powder form to liquid form through melting at around 447 °C. The melting point of TeO₂ is 730°C which is decreased due to the presence of Na₂CO₃ mixed with ZnO [18]. The glass transition temperature (T_g) of pure and doped NZT glass materials has been observed to be 284°C and 275°. The decreased value of T_g of the doped sample indicates onward formation of stable glass material. The thermal stability of the glasses is generally defined as a difference between glass transition temperature and crystallization temperature. Here, the estimated thermal stabilities (ΔT) of the pure and Sm³⁺ doped NZT glass materials have been tabulated in table 1. Glass thermal stability is stronger for a glass host to have ΔT as large as possible [17, 19]. The result specified here that the prepared Sm³⁺ doped NZT glass holds good anti-crystallization ability and thermal stability. The glass-forming tendency can be explained using Eq. (1), where H is Hruby's parameter [20, 21].

$$H = \frac{Tc - Tg}{Tm - Tc}.$$
 (1)

The higher value of Hruby's parameter in the case of Sm_2O_3 doped NZT glass sample indicates the improvisation of glass-forming tendency due to doping of Sm^{3+} ions.

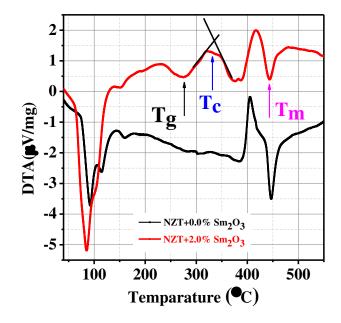


Figure 3 TG with DTG curve of the pure and Sm₂O₃ doped NZT glasses.

Figure 3 shows the TG with DTG pattern of the pure and Sm₂O₃ doped NZT glasses. The weight loss of the precursor mixture has been observed for pure and doped glasses at different temperatures. TG/DTG curve illustrates the 5.37 % mass loss out of total mass due to exclusion of water, the release of moisture and other volatile substances in the temperature region 58-127 °C [22, 23]. The CO₂ is removed at the temperature range 380 °C to 406 °C for the decomposition of Na₂CO₃which is found from DTG curves for pure and doped samples. A little amount of mass is also lost within the temperature range of 435 °C to 450°C during the melting of the solid materials. No weight loss is detected beyond the temperature of 450 °C.

3.2. XRD

X-ray diffractogram of pure NZT and Sm_2O_3 doped glasses are shown in Fig. 4. It has been found from the figure that the XRD of all the samples demonstrate no discrete sharp peaks and a broad peak has been found in the region of the glancing angle at 24° to 34°. This broad peak in the XRD pattern indicates the non-crystalline materials as characteristics of typical longrange structural disorder of the samples. The broad continuous pattern of X-ray diffraction reveals the amorphous nature of these glasses [24, 25].

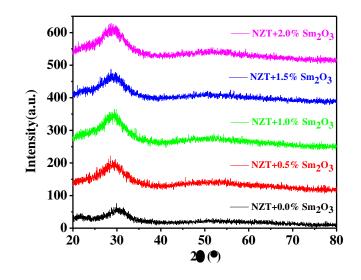


Figure 4 XRD pattern of sample pure and Sm³⁺ doped with NZT glass materials.

3.3. Optical Property

3.3.1. FTIR spectroscopy

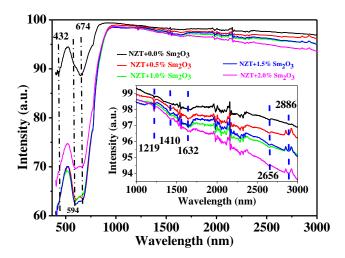


Figure 5 FTIR spectroscopy of pure and various Sm³⁺ doped with NZT glass materials.

Figure 5 represents the FTIR transmission spectra of pure and Sm_2O_3 doped NZT glasses in the wave number range 400-3000 cm⁻¹ at room temperature. The band at 424-440 cm⁻¹ comes out due to the symmetric stretching vibration of the Zn-O bond. Zn²⁺ ions perform as an agent to split bonds and generate a modification in the glass structure. For this result, TeO₃₊₁ and TeO₃ can be twisted from TeO₄ units making non-bridging oxygen atoms [26-28]. This is also confirmed from the observation of glass transition temperature in DTA. The band is located at 570–601 cm⁻¹due to the stretching vibration of TeO₄ (trigonal pyramid) [29, 30]. It is observed that transmission intensity slightly changes due to the presence of Sm₂O₃ in the glass system. The band at 670–685 cm⁻¹ is observed due to the stretching vibration of TeO₄ trigonalbipyramid (tbp) [29]. The fundamental groups such as (- OH) bond, hydrogen bond and H-O-H bending appear in the higher region at 1632cm⁻¹[31]. The broad shoulder corresponds to the hydrogen bonds are observed around 2886 cm⁻¹.

3.3.2. Absorption spectroscopy

UV/Viz absorption spectra of pure and Sm_2O_3 -doped NZT glasses are displayed in Fig. 6. The recording of absorption intensity has occurred in the visible range (350 - 540 nm) at room temperature with the band assignments. It is found from fig. 6, the absorption intensity increases gradually with the increase of doping concentration of Sm_2O_3 . There is no transition occurred for the pure NZT glass sample whereas the absorption peaks are appeared at specific transitions in the case of Sm^{3+} ions doping. The tail of the optical absorption band is not strongly identified due to the amorphous nature of glasses which is also established from XRD. The peak value of Sm^{3+} doped NZT samples is obtained for the interaction of 4f -5d electronic configurations [32]. It is observed that there are four absorption peaks for the transitions ${}^6\text{H}_{5/2}$ - ${}^4\text{P}_{3/2}$ at 402 nm, ${}^6\text{H}_{5/2}$ -

 ${}^{4}M_{19/2}$ at 418 nm, ${}^{6}H_{5/2}$ - ${}^{4}I_{15/2}$ at 462 nm and ${}^{6}H_{5/2}$ - ${}^{4}I_{11/2}$ at 478 nm. Carnall et al. approved these transitions [33, 34].

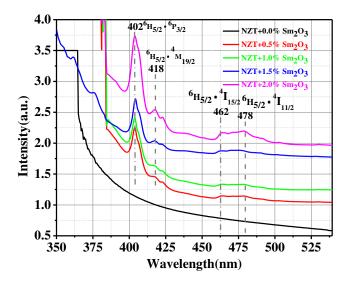


Figure 6 Absorption spectroscopy of pure and Sm³⁺ doped with NZT glass materials.

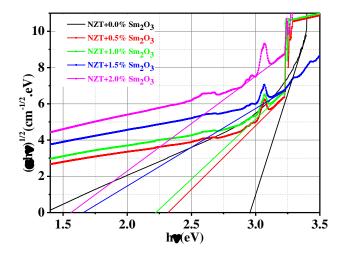


Figure 7 Tauc's plot for pure and Sm³⁺ doped with NZT glass materials.

Figure 7 shows the variation of absorption coefficient $\alpha(v)$ with corresponding energy. The absorption coefficient in many non-crystalline materials reflects the density of states at the band tails and can be determined from the optical absorption spectra using Eq. (2)

$$\alpha(v) = \left(\frac{A}{t}\right) \dots \dots \dots (2)$$

Where $\alpha(v)$ is the absorption coefficient, A is the absorbance and t is the width of the sample

$$\alpha(\nu) = \frac{A(h\nu - E_g)^m}{h\nu} \dots \dots (3)$$

Table 2 Band gap energy, refractive index and other physical properties of pure and Sm³⁺ doped

Samples	Band gap	Refractive	Inter Molecular	Polaron	Field	Ion
Name	energy E _g	index(n)	distance	Distance	strength(F)	density
	(eV)		(r _i) in Å	(r _p) in Å	$\times 10^{16}$	density $\times 10^{20}$
NZT+0.0%	2.95	2.41				
Sm_2O_3						
NZT+0.5%	2.28	2.63	14.98	6.037	4.125	2.97
Sm_2O_3						
NZT+1.0%	2.22	2.65	13.86	5.586	4.819	3.76
Sm_2O_3						
NZT+1.5%	2.12	2.69	19.51	7.862	2.432	1.35
Sm_2O_3						
NZT+2.0%	1.58	2.95	20.41	8.228	2.220	1.18
Sm ₂ O ₃						

NZT glasses.

Equation (3) gives the relation between absorption coefficient and photon energy. It has been determined the value of indirect band gap energy for m = 2 from the above equation (2) by plotting the absorption coefficient to zero absorption in the graph $(\alpha hv)^{1/2}$ vs hv. For the indirect transitions, the corresponding value of E_g is obtained by extrapolating $(\alpha hv)^{1/2} = 0$. The values of E_g for the glasses are tabulated in table 1. The decrease of E_g with increasing Sm³⁺ ions in the glass network can be explained by the creation of large number of NBO in the samples. The

negative charges of oxygen ions in the NBO create active electrons with a higher value than that on the bridging oxygen (BO). These active electrons are distributed irregularly as because NBO's are softly bounded by the tellurite atoms [34-36].

The obtained values of the E_g and the refractive index (n) can be estimated using Eq. (4) [36, 37].

$$\frac{n^2 - 1}{n^2 + 2} = 1 - \sqrt{\frac{E_g}{20}} \dots \dots \dots (4)$$

Refractive index increases with the increasing number of Sm³⁺ ions due to the creation of nonbridging bonds. This effect can be explained by the dissociation of the bridging Te–O–Te bonds and created non-bridging bonds. The bond energies of non-bridging oxygen (NBO) bonds are lower with greater ionic character. The cation refractions have a higher magnitude for the NBO bonds are determined from this explanation [37].

3.3.3 Fluorescence Spectra

Figure 8 shows the fluoresce emission spectra for different concentrations of Sm_2O_3 doped with NZT glasses. The spectra have been recorded for samples with four different concentrations of Sm^{3+} ions at an excitation wavelength 402 nm in the visible range of 500 - 700 nm at room temperature.

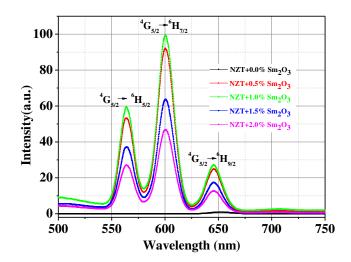


Figure 8 Luminescence spectra of pure and Sm³⁺ doped with NZT glass materials, excited at 402 nm.

Figure 8 displays the three peaks at the wavelengths 563 nm (green), 600 nm (orange) and 645 nm (red) with the matching to the transitions ${}^{4}G_{5/2} \rightarrow {}^{6}H_{5/2}$, ${}^{4}G_{5/2} \rightarrow {}^{6}H_{7/2}$, ${}^{4}G_{5/2} \rightarrow {}^{6}H_{9/2}$ of Sm³⁺ ions respectively [16, 32, 38-40]. It is found that the emission band at 600 nm (${}^{4}G_{5/2} \rightarrow {}^{6}H_{7/2}$) is the most outstanding band in all Sm₂O₃ doped NZT glasses.

The higher intensity of allowed transition ${}^{4}G_{5/2} \rightarrow {}^{6}H_{7/2}$ (600 nm) is occurred due to the contribution of magnetic dipole in the Sm³⁺doped NZT glasses. In comparison to the intensity of the three emission peaks, the magnetic transition (${}^{4}G_{5/2} \rightarrow {}^{6}H_{7/2}$) is greater than the intensity of electric dipole transitions (${}^{4}G_{5/2} \rightarrow {}^{6}H_{5/2}$) and (${}^{4}G_{5/2} \rightarrow {}^{6}H_{9/2}$) due to the ionic nature and symmetry of the system. The melt quenching of Sm³⁺ doped NZT glass samples has also been confirmed from the emission band according to the increasing and decreasing intensity conforming to the quenching effect of various doping concentrations. Usually, the quenching effect is created from the non-radiative method consisting of multi-phonon relaxation and the non-radiative cross-

relaxation may be obtained by two Sm^{3+} ions through dipole-quadrupole or dipole-dipole or quadrupole-quadrupole interactions [41-45].

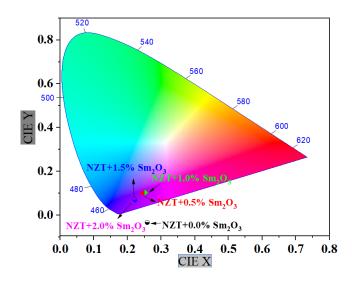


Figure 9 CIE chromaticity color coordinate diagram of Sm³⁺ doped with NZT glass materials, excited at 402 nm.

The scattering wavelengths of emission in the visible area can be quantified using CIE 1931 colour coordinates, which is a physiologically apparent colour vision of humans. The emission band of Sm_2O_3 doped NZT glass samples were plotted using CIE 1931 (Fig. 9). The obtained colour confirmed the different colours of emission of all materials. The colour coordinates was (0.25839, -0.03215), (0.2526, 0.1042), (0.21879, 0.06764), (0.24418, 0.1011), and (0.22123, 0.0711) for Sm³⁺ doped (0.5% wt-2% wt) respectively. The non-emissive nature of the pure glass sample was confirmed from coordinates out the CIE plot. The changes in coordinates indicated that with increasing rare-earth oxide percent the emission shifted towards higher wavelengths.

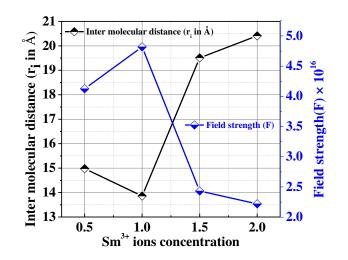


Figure 10 Variation of intermolecular distance and field strength with Sm³⁺ ions concentration.

$$r_{i} = \left(\frac{1}{N}\right)^{\frac{1}{3}} \dots \dots \dots \dots (5)$$
$$r_{p} = \left(\frac{\pi}{6N}\right)^{\frac{1}{3}} \dots \dots \dots (6)$$
$$F = \left(\frac{Z}{r_{p}^{2}}\right) \dots \dots \dots (7)$$

Figure 10 shows the variation of inter-ionic distance (r_i) and field strength (F) with ion concentration of Sm³⁺ ions. Inter ionic distance (r_i) and polaron distance (r_p) decrease up to 1 wt% doping concentration of Sm³⁺ ions. The field strength (F) between Sm³⁺- Sm³⁺ ions are increased with the ion concentration up to 1 wt% of Sm³⁺ ions are obtained using Eq. (7). Again, the inter-ionic and polaron distance increase up to 2 wt% of Sm³⁺ ions and correspondingly the field strength (F) decreases due to the variation of Sm³⁺ ions which confirmed the fluoresce emission spectra. As the inter-ionic distance (r_i) decreases between two Sm³⁺ ions for the compactness of glass structure, the strong interaction of Sm³⁺ ions can transfer the excitation energy from one Sm³⁺ ion to the other [32].

3.3.4. Cross Section

The absorption cross-section of the glass materials for the ${}^{4}G_{5/2}-{}^{6}H_{7/2}$ transition has been measured using Lambert-Beer formula

$$\sigma_{ab}(\lambda) = 2.303 \frac{A}{Nt} \dots \dots (8)$$

Where A is absorbance, t is the width of the glass sample and N is the density (ions/cm³) of Sm³⁺ ions of the telluride glass. Figure 11 shows the absorption cross-section is increasing for increasing the concentration of Sm³⁺ ions in the NZT glass samples. The emission cross-section σ_{emi} is calculated using MaCumber (1964) theory [46].

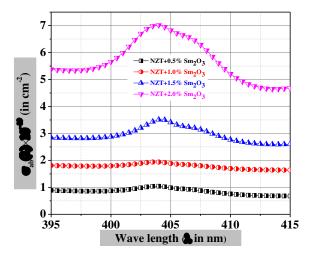


Figure 11 Wavelength dependence absorption cross-section of Sm_2O_3 doped NZT glass materials.

The absorption and emission cross-section are related with the formula

$$\sigma_{emi}(\lambda) = \sigma_{ab}(\lambda) exp\left[\frac{Eg-hv}{K_BT}\right] \dots \dots \dots (9)$$

Where v be the photon frequency, E_g is the free energy needed to excite Sm³⁺ from ${}^{4}G_{5/2}-{}^{6}H_{7/2}$ state at temperature T, h is the Planck's constant, and K_B is the Boltzmann constant. Figure 12 shows the emission cross-section of Sm³⁺ doped glasses for the ${}^{4}G_{5/2}-{}^{6}H_{7/2}$ transition. The emission cross-section of Sm³⁺doped NZT glasses is increased due to the higher concentration of Sm³⁺ ions.

The emission cross-section (σ_{emi}) is the main parameter and its value suggests the rate of energy removal from the lasing material [44]. The higher value of emission cross-section proposes the interesting characteristic for high gain laser applications, low threshold, which are applied to achieve constant wave (CW) laser action.

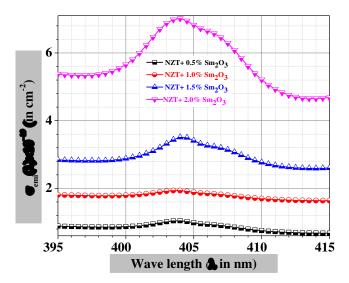


Figure 12 Wavelength dependence emission cross-section of Sm₂O₃ doped NZT glasses.

3.4. Dielectric Property

3.4.1. Dielectric Constant

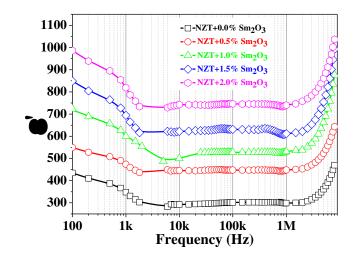


Figure 13 Dielectric constant (ϵ') for Sm³⁺ doped NZT at room temperature.

The values of the dielectric constant are correlated to the electron density and ionic charges. The effect of frequency on dielectric constant for Sm_2O_3 doped NZT glass is observed in Fig. 13 for the frequency range100 Hz - 8 MHz at room temperature. It has been observed that the magnitude of ε' decreases swiftly with increasing frequency of 100 Hz to 2 kHz. This could be attributed to the dielectric dispersion resulting from the delay of the polarization process of the molecules behind the interchanges of the applied electric field [47]. At low frequency, the increase of dielectric constant is also ascribed to the electronic, ionic, dipolar, interfacial polarization and the absence of spontaneous polarization [20, 48]. The magnitude of ε' of these glasses is almost constant in the frequency region 3 kHz – 2MHz due to the decrease of ionic, space charge and orientation polarization. It has been also described that the pure and doped glasses are not maintaining any variation of dielectric constant with frequency because of the stable molecular orientation and the electron exchange between the ions does not follow high frequency applied field. On the other hand, this may be explained as the applied frequency increases, the ions are not able to respond quickly and it reveals an almost frequency independent

behavior may be due to the diminishing number of dipoles which contributes to polarization in the high-frequency region [49].

The dielectric constant increases rapidly beyond the frequency region 2 MHz [50]. It has been observed that the dielectric constant increases from 430 to 980 for Sm_2O_3 doping in the lower frequency as well as advanced frequency. This effect may be explained by the charge accumulation due to rare-earth doping. The increasing concentration of doped ions disrupts the tellurite glass system by producing dangling bonds and NBOs. These bonds and NBOs create the motion of charges and thus generate space charge polarization leading to a sharp rise in the dielectric constant [48]. This result is similar to Eu³⁺ doped NZT glass materials [51].

3.4.2. DC Conductivity

The variation of electrical conductivity as a function of temperature is shown in fig. 14. The conductivity increases with temperature and also with the doping concentration of Sm^{3+} ions concentration. This variation of conductivity with temperature establishes that the electrical conduction mechanism is Arrhenius type. This Arrhenius mechanism of electrical dc conductivity can be applied to determine the activation energy of the samples using the connection

$$\sigma_{dc} = \sigma_0 exp^{\frac{E_a}{K_B}}T \quad \dots \quad \dots \quad (10)$$

Where E_a is the activation energy, σ_0 denotes the pre-exponential factor, T is the absolute temperature and K_B is the Boltzmann constant. The assessed activation energies for these samples have been measured from fig. 14. The activation energy reduces (0.63 eV to 0.43 eV) due to the doping of Sm³⁺ ions. The collaboration between the rare-earth ions and structural units of host glass clarified the increment of dc conductivity due to the

increasing concentration of rare-earth ions [51]. The technique of conductivity in the glass structure is defined by doping concentration, atomic weight and position of Sm³⁺ ions. The doping concentration of rare-earth ions generates a huge number of NBO in the tellurite glass materials which is also established from FTIR spectra for Sm³⁺ doped NZT glass materials. The higher concentrations of Sm³⁺ ions in the NZT glasses enhance the creation of NBO atoms and hence the conductivity is improved for all the glass materials



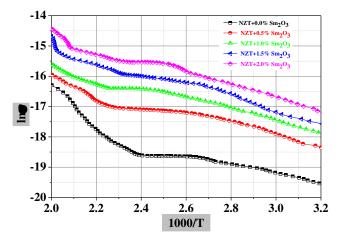


Figure 14 Arrhenius mechanism of $\ln \sigma$ vs 1000/T.

4. Conclusions

Samarium (III) doped NZT glasses have been efficiently prepared by the melt-quenching method. The X-ray diffraction characterization indicates the amorphous nature of the glass materials for the higher doping concentration of Sm^{3+} ions. FTIR spectra reveal the construction of a new glass structure of pure and Sm_2O_3 incorporated NZT glasses. The stability of the glass sample is examined by using Hruby's parameter (H) and thermal stability ΔT from the DTA curve. The value of H is 0.57 for highest glass stability in the higher doping of Sm^{3+} ions. The refractive index increases 2.41 to 2.95 with the increase of Sm^{3+} ions. The absorption bands of the glass materials are found corresponding to the transitions ${}^{6}\text{H}_{5/2}$ - ${}^{4}\text{P}_{3/2}$ at 402 nm, ${}^{6}\text{H}_{5/2}$ - ${}^{4}\text{M}_{19/2}$ at

418 nm, ${}^{6}H_{5/2}{}^{-4}I_{5/2}$ at 462 nm and ${}^{6}H_{5/2}{}^{-4}I_{11/2}$ at 478 nm. The emissions at 563 nm, ${}^{4}G_{5/2}{}\rightarrow {}^{6}H_{5/2}$, at 600 nm, ${}^{4}G_{5/2}{}\rightarrow {}^{6}H_{7/2}$, at 645nm, ${}^{4}G_{5/2}{}\rightarrow {}^{6}H_{9/2}$ is observed in the photoluminescence spectra. Field strength (F) increases with increasing the Sm³⁺ ions concentration and consequently, the interionic distance (r_i) and polaron radius (r_p) are observed to decrease. The magnitude of indirect E_g is decreased to the change in the structure of such glasses. The dielectric constant of Sm₂O₃ doped NZT glasses has been measured for various frequencies and found as a stable substance within the frequency of 3 kHz-2 MHz. The dc conductivity increases with temperature whereas the activation energy decreases with the increase of ion concentration in the usual manner. So, Sm₂O₃ doped NZT glass samples have a large prospect for application in optoelectronic devices.

Acknowledgement

The work is partly maintained by DST Govt. of West Bengal research project (Memo No.: 296 (Sanc)/ST/P/S&T/16G- 17/2017) of India. The authors want to thank the CRF, IIT Kharagpur for providing facilities to study DTA and TGA. The authors desire to express thanks to Jadavpur University for providing facilities to study FTIR.

References

 [1] Hisam R, Yahya AK, Kamari HM, Talib ZA, Subban RHY. Anomalous dielectric constant and AC conductivity in mixed transition-metal-ion xFe₂O₃-(20-x)MnO₂-80TeO₂ glass system.
 Mater. Express 2016;6(2):149-160.

[2] Moraes JCS, Nardi JA, Sidel SM, Mantovani BG, Yukimitu K, Reynoso VCS, Malmonge LF, Ghofraniha N, Ruocco G, Andrade LHC, Lima SM. Relation among optical, thermal and

thermo-optical properties and niobium concentration in tellurite glasses. J. Non-Crys. Solids 2010;356(41-42): 2146-2150.

[3] Rajendran V, Palanivelu N, Chaudhuri BK, Goswami K. Characterisation of semiconducting V_2O_5 -Bi₂O₃-TeO₂ glasses through ultrasonic measurements. J. Non Cryst. Solids 2003;320(1-3):195-209.

[4] Hajer SS, Halimah MK, Azmi Z, Azlan MN. Optical properties of zinc-borotellurite doped samarium. Chalcogenide Lett. 2014;11(11):553-566.

[5] Eraiah B. Optical properties of samarium doped zinc-tellurite glasses. Bull. Mater. Sci. 2006;29(4):375-378.

[6] Munishwar SR, Roy K, Gedam RS. Photolumincence study of Sm³⁺ containing sodium borosilicate glasses and glass-ceramics. Mater. Res. Express 2017;4(10):105201-1-8.

[7] Stambouli W, Elhouichet H, Gelloz B, Ferid M. Optical and spectroscopic properties of Eudoped tellurite glasses and glass ceramics. J. Lumin. 2013;138, 201-208.

[8] Gedam RS, Ramteke DD. Electrical and optical properties of lithium borate glasses doped with Nd₂O₃. J. Rare-earths 2012;30(8):785-788.

[9] Ramteke DD, Annapurna K, Deshpande VK, Gedam RS. Effect of Nd³⁺ on spectroscopic properties of lithium borate glasses. J. Rare-earths 2014;32(12):1148-1153.

[10] Lurin C, Parent C, Leflem G, Hagenmuller P. Energy transfer in a Nd³⁺-Yb³⁺ borate glass.
J. Phys. Chem. Solids 1985;46(9):1083-1092.

[11] Surana SSL, Sharma YK, Tandon SP. Laser action in neodymium-doped zinc chloride borophosphate glasses. Mater. Sci. Eng. B 2001;83:204-209.

[12] Babu P, Jang KH, Kim ES, Shi L, Seo HJ. Optical Properties and White-Light Emission in Dy³⁺-Doped Transparent Oxyfluoride Glass and Glass Ceramics Containing CaF₂ nanocrystals.
 J. Korean Phys. Soc. 2009;54(4):1488-1491.

[13] Ramteke DD, Gedam RS. Spectroscopic properties of dysprosium oxide containing lithium borate glasses. Spectrosc. Lett. 2015;48(6):417-421.

[14] Dawaud RSES, Hashim S, Alajerami YSM, Mhareb MHA, Maqableh MM. Structural and optical properties of lithium sodium borate glasses doped with Sm³⁺ ions. Int. J. Mod. Phys. B 2014;28(26):1450182-1-12.

[15] Lin H, Pun EYB, Wang X, Liu X. Intense visible fluorescence and energy transfer in Dy³⁺, Tb³⁺, Sm³⁺ and Eu³⁺ doped rare-earth borate glasses. J. Alloys Compound. 2005;390(1-2):197-201.

[16] Marzouk MA, Batal HAE, Hamdy YM, Eldin FME. Collective Optical, FTIR, and Photoluminescence Spectra of CeO₂ and/or Sm₂O₃-Doped Na₂O–ZnO–P₂O₅ Glasses. Int. J. Optics. 2019;1-11.

[17] Mawlud SQ, Ameen MM, Sahar MR, Ahmed KF. Influence of Sm₂O₃ ion concentration on structural and thermal modification of TeO₂-Na₂O glasses. J Appl. Mech. Eng. 2016;5(5):1-5.

[18] Kalampounias AG, Tsilomelekis G, Boghosian S. Glass-forming ability of TeO_2 and temperature induced changes on the structure of the glassy, super cooled and molten states. J. Chem. Phys. 2015;142:154503-1-11.

[19] Baki SO, Tan LS, Kan CS, Kamari HM, Noor ASM, Mahdi MA. Structural and optical properties of $\text{Er}^{3+}-\text{Yb}^{3+}$ co-doped multi-composition TeO₂-ZnO-PbO-TiO₂-Na₂O glass. J. Non Cryst. Solids 2013;362:156-161.

[20] Wang M, Yi L, Zhang L, Wang G, Hu L, Zhang J. 2-μm fluorescence and Raman spectra in high and low Al(PO₃)₃ content fluorophosphates glasses doped with Er-Tm-Ho, Chin. Opt. Lett. 2009;7(11):1035-1037.

[21] Jr AAC, Fredericci C, Zanotto ED. A test of the Hruby parameter to estimate glass-forming ability J. Non-Cryst. Solids 1997;219:182-186.

[22] Khalil MI, Qunaibit MMA, Zahem AMA, Labis JP. Synthesis and characterization of ZnO nanoparticles by thermal decomposition of a curcumin zinc complex. Arab. J. Chem. 2014;7(6):1178-1184.

[23] Badamasi S, Tanko YA. Thermal properties of TeO₂-ZnO-Na₂O glasses: effect of Dy₂O₃ doping. Sci. World J. 2018;13(4):95-99.

[24] Azlan MN, Halimah MK, Hajer SS, Suriani AB, Azlina Y, Umar SA. Enhanced optical performance of tellurite glass doped with samarium nanoparticles for fiber optics application. Chalcogenide Lett. 2019;16(5):215-229.

[25] Azlan MN, Hajer SS, Halimah MK, Umar SA, Zaid MHM, Hisam R, Iskandar SM, Kenzhaliyev BK, Kassymova GK, Yusof NN. Comprehensive comparison on optical properties of samarium oxide (micro/nano) particles doped tellurite glass for optoelectronics applications. Res. Sq. 2021;

[26] Elkhoshkhanya N, Marzouk SY, Khattab MA, Dessouki SA. Influence of Sm₂O₃ addition on Judd-Ofelt parameters, thermal and optical properties of the TeO₂-Li₂O-ZnO-Nb₂O₅ glass system. Mater. Charact. 2018;144:274-286.

[27] Ahmmad SK, Samee MA, Taqiullah SM, Rahman S. FT-IR and Raman spectroscopic studies of ZnF₂–ZnO–As₂O₃–TeO₂ glasses. J. Taibah Univ. Sci. 2016;10(3):329-339.

[28] Marjanovic S, Toulouse J, Jain H, Sandmann C, Dierolf V, Kortan AR, Kopylov N, Ahrens RG. Characterization of new erbium-doped tellurite glasses and fibers. J. Non Cryst. Solids 2003;322(1-3):311-318.

[29] Mansour SF, Yousef ES, Hassaan MY, Emara AM. Thermal, IR, Raman characteristics, Raman gain coefficient and bandwidths in quaternary glasses. Solid State Sci. 2014;37:33-39.

[30] Elkhoshkhany N, Khatab MA, Kabary MA. Thermal, FTIR and UV spectral studies on Tellurite Glasses doped with Cerium Oxide. Ceram. Int. 2018;44(3):2789-2796.

[31] Hasim N, Rohani MS, Sahar MR. Structural Characteristics of Er³⁺ and Nd³⁺ doped Lithium Niobate Tellurite Glass, *Mater. Sci. Forum* 2017, 846, 126.

[32] Ramteke DD, Ganvir VY, Munishwar SR, Gedam RS, Concentration Effect of Sm³⁺ ions on structural and luminescence properties of lithium borate glasses. Phys. Procedia, 2015;76:25-30.

[33] Carnall WT, Fields PR, Rajnak K. Electronic Energy Levels in the Trivalent Lanthanide Aquo Ions. I. Pr³⁺, Nd³⁺, Pm³⁺, Sm³⁺, Dy³⁺, Ho³⁺, Er³⁺ and Tm³⁺, J. Chem. Phys. 1968;49(10):4424-4442.

[34] Mawlud SQ, Ameen MM, Sahar MR, Yusof NM, Ahmed KF, Tanko YA. Absorption and luminescence spectral properties study of sm³⁺ doped Teo₂-Na₂o glasses. Proc.Int. Sci. Postgraduate Conf. 2016;1-10.

[35] Shwetha M, Eraiah B. Influence of samarium ions (Sm³⁺) on the optical properties of lithium zinc phosphate glasses. AIP Conf. Proc. 2018;1953:090002-1-4.

[36] Upender G, Ramesha S, Prasada M, Sathe VG, Mouli VC. Optical band gap, glass transition temperature and structural studies of (100–2x)TeO₂–xAg₂O–xWO₃ glass system. J. Alloys Compound. 2010;504(2):468-474.

[37] Mohamed EA, Ahmad F, Aly KA. Effect of lithium addition on thermal and optical properties of zinc-tellurite glass. J. Alloys Compound. 2012;538:230-236.

[38] Arunkumar S, Marimuthu K. Concentration effect of Sm³⁺ ions in B₂O₃–PbO–PbF₂–Bi₂O₃– ZnO glasses – structural and luminescence investigations. J. Alloys Compd. 2013;565:104-114.

[39] Kesavulu CR, Jayasankar CK. Concentration effect of Sm^{3+} ions in B₂O₃–PbO–PbF₂– Bi₂O₃–ZnO glasses – structural and luminescence investigations. J. Lumin. 2012;132(10):2802-2809.

[40] Sundari SS, Marimuthu K, Sivraman M, Babu SS, Composition dependent structural and optical properties of Sm³⁺-doped sodium borate and sodium fluoroborate glasses. J. Lumin. 2010;130(7):1313-1319.

[41] Reddy KSRK, Swapna K, Mahamuda S, Venkateswarlu M, Prasad MVVKS, Rao AS, Prakash GV. Composition dependent structural and optical properties of Sm³⁺ doped sodium borate and sodium fluoroborate glasses. Opt. Mater. 2018;79:21-32.

[42] Lavın V, Martın IR, Jayasankar CK, Troster T, Pressure-induced energy transfer processes between Sm³⁺ ions in lithium fluoroborate glasses. Phys. Rev. B 2002;66:064207-1-7.

[43] Thomas S, George R, Rasool SN, Rathaiah M, Venkatramu V, Joseph C, Unnikrishnan NV. Optical properties of Sm^{3+} ions in zinc potassium fluorophosphate glasses, Opt. Mater. 2013;36(2):242-250.

[44] Suhasini T, Kumar JS, Sasikala T, Jang K, Lee HS, Jayasimhadri M, Jeong JH, Yi SS, Moorthy LR. Absorption and fluorescence properties of Sm³⁺ ions in fluoride containing phosphate glasses. Opt. Mater. 2009;31(8):1167-1172.

[45] Solarz P, Romanowski WR, Luminescence and energy transfer processes of Sm^{3+} in $K_5\text{Li}_2\text{LaF}_{10}:\text{Sm}^{3+}-K_5\text{Li}_2\text{SmF}_{10}$ single crystals. Phys. Rev. B 2005;72:075105-1-8.

[46] Mandal D, Banerjee HD, Goswami MLN, Acharya HN. Synthesis of Er^{3+} and Er^{3+} : Yb³⁺ doped sol–gel derived silica glass and studies on their optical properties, Bull. Mater. Sci. 2004;27(4):367-372.

[47] Ibrahim SE, Rammah YS, Hager IZ, Mallawany RE, UV and electrical properties of TeO₂ WO₃-Li₂O-Nb₂O₅/Sm₂O₃/Pr₆O₁₁/ Er₂O₃ glasses. J. Non-Cryst. Solids 2018;498:443-447.

[48] Zulkefly SS, Kamari HM, Azis MNA, Yusoff WMDW. Influence of erbium doping on dielectric properties of zinc borotellurite glass system. Mater. Sci. Forum. 2015;846:161-171.

[49] Graca MPF, Fawzy H, Badr Y, Elokr MM, Nico C, Soares R, Costa LC, Valente MA. Electrical, dielectric and structural properties of borovanadate glass systems doped with samarium oxide. Phys. Status Solidi C 2011;8(11-12):3107-3110.

[50] Li HM, Ra CH, Zhang G, Yoo WJ. Frequency and temperature dependence of the dielectric properties of a PCB substrate for advanced packaging applications. J. Korean Phys. Soc. 2009;54(3):1096-1099.

[51] Mirdda JN, Mukhopadhyay S, Sahu KR, Goswami, Enhancement of optical emission and dielectric properties of Eu^{3+} -doped Na_2o –ZnO–TeO₂ glass material. Glass Phys. Chem. 2020;46(3):218-227.

[52] Ali AA, Shaaban MH. Electrical properties of LiBBaTe glass doped with Nd₂O₃. Solid State Sci. 2010;12(12):2148-2154.

Figure captions:

Figure 1 Picture of Sm₂O₃ doped NZT glass sample.

Figure 2 DTA curves of Sm₂O₃ doped NZT glass samples.

Figure 3 TG with DTG curve of the pure and Sm₂O₃ doped NZT glasses.

Figure 4 XRD pattern of sample pure and Sm³⁺ doped with NZT glass materials.

Figure 5 FTIR spectroscopy of pure and various Sm³⁺ doped with NZT glass materials.

Figure 6 Absorption spectroscopy of pure and Sm³⁺ doped with NZT glass materials.

Figure 7 Tauc's plot for pure and Sm³⁺ doped with NZT glass materials.

Figure 8 Luminescence spectra of pure and Sm³⁺ doped with NZT glass materials, excited at 402 nm.

Figure 9 CIE chromaticity color coordinate diagram of Sm³⁺ doped with NZT glass materials, excited at 402 nm.

Figure 10 Variation of intermolecular distance and field strength with Sm³⁺ ions concentration.

Figure 11 Wavelength dependence absorption cross-section of Sm₂O₃ doped NZT glass materials.

Figure 12 Wavelength dependence emission cross-section of Sm_2O_3 doped NZT glasses. Figure 13 Dielectric constant (ϵ') for Sm^{3+} doped NZT at room temperature.

Figure 14 Arrhenius mechanism of $\ln \sigma$ vs 1000/T.

Table captions:

Table 1 Thermal parameters calculated from the DTA traces of pure and Sm_2O_3 doped NZT glasses.

Table 2 Band gap energy, refractive index and other physical properties of pure and Sm³⁺ doped NZT glasses.

Sample Name	$T_{g}(^{\circ}C)$	$T_{c}(^{\circ}C)$	T_m (°C)	$\Delta T = T_c - T_g$	$H = (T_c - T_g)/(T_m - T_c)$
NZT+0.0% Sm ₂ O ₃	284	328	447	122	0.37
NZT+2.0% Sm ₂ O ₃	275	336	443	61	0.57

Table 2

Samples Name	Band gap energy E _g (eV)	Refractive index(n)	Inter Molecular distance (r _i) in Å	Polaron Distance (r _p) in Å	Field strength(F) $\times 10^{16}$	Ion density $\times 10^{20}$
NZT+0.0% Sm ₂ O ₃	2.95	2.41				
NZT+0.5% Sm ₂ O ₃	2.28	2.63	14.98	6.037	4.125	2.97
NZT+1.0% Sm ₂ O ₃	2.22	2.65	13.86	5.586	4.819	3.76
NZT+1.5% Sm ₂ O ₃	2.12	2.69	19.51	7.862	2.432	1.35
NZT+2.0% Sm ₂ O ₃	1.58	2.95	20.41	8.228	2.220	1.18

Table 1